General Description

The MAX4741/MAX4742/MAX4743 are low on-resistance, low-voltage, dual single-pole/single-throw (SPST) analog switches that operate from a single +1.6V to +3.6V supply. These devices have fast switching speeds (toN = 24ns, tOFF = 16ns max), handle Rail-to-Rail[®] analog signals, and consume less than 1µW of quiescent power. The MAX4743 has break-beforemake switching.

When powered from a +3V supply, the MAX4741/ MAX4742/MAX4743 feature low 0.8Ω (max) on-resistance (R_{ON}), with 0.08Ω (max) R_{ON} matching and 0.18Ω R_{ON} flatness. The digital logic input is 1.8V CMOS compatible when using a single +3V supply.

The MAX4741 has two normally open (NO) switches, the MAX4742 has two normally closed (NC) switches, and the MAX4743 has one NO switch and one NC switch. The MAX4741/MAX4742/MAX4743 are available in 8-pin SOT23 and 8-pin μ MAX packages.

Applications

- Power Routing
- Battery Powered Systems
- Audio and Video Signal Routing
- Low-Voltage Data-Acquisition Systems
- Communications Circuits
- PCMCIA Cards
- Cellular Phones
- Modems
- Hard Drives

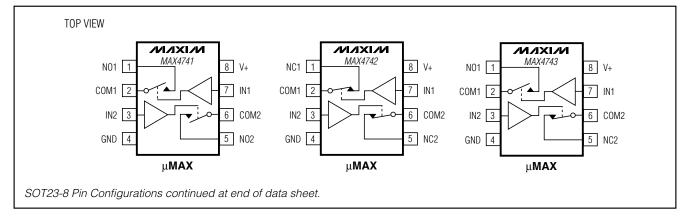
__Features

- Low R_{ON}: 0.8Ω max (+3V Supply) 2.5Ω max (+1.8V Supply)
- 0.18Ω max Ron Flatness (+3V Supply)
- +1.6V to +3.6V Single-Supply Operation
- Available in SOT23 and µMAX Packages
- High-Current Handling Capacity (150mA continuous)
- 1.8V CMOS Logic Compatible (+3V Supply)
- ♦ Fast Switching: toN = 24ns, toFF = 16ns

Ordering Information

PART	TEMP. RANGE	PIN- PACKAGE	TOP MARK
MAX4741EKA	-40°C to +85°C	8 SOT23-8	AAIY
MAX4741EUA	-40°C to +85°C	8 μΜΑΧ	_
MAX4742EKA	-40°C to +85°C	8 SOT23-8	AAIZ
MAX4742EUA	-40°C to +85°C	8 μΜΑΧ	_
MAX4743EKA	-40°C to +85°C	8 SOT23-8	AAJA
MAX4743EUA	-40°C to +85°C	8 µMAX	_

Pin Configurations



Rail-to-Rail is a registered trademark of Nippon Motorola, Inc.

____ Maxim Integrated Products 1

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

ABSOLUTE MAXIMUM RATINGS

Voltages Referenced to GND

Voltagee Helefelleea te al 12
V+, IN0.3V to +4V
COM_, NO_, NC_ (Note 1)0.3V to (V+ + 0.3V)
Continuous Current COM_, NO_, NC±150mA
Peak Current COM_, NO_, NC_
(pulsed at 1ms 10% duty cycle)±300mA
Continuous Power Dissipation ($T_A = +70^{\circ}C$)
8-Pin SOT23 (derate 7.52mW/°C above +70°C)602mW
8-Pin µMAX (derate 4.5mW/°C above +70°C)

Operating Temperature Range	40°C to +85°C
Maximum Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Note 1: Signals on COM_, NO_, or NC_ exceeding V+ or GND are clamped by internal diodes. Limit forward current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Single +3V Supply

(V+ = +2.7V to +3.6V, V_{IH} = +1.4V, V_{IL} = +0.5V, T_A = T_{MIN} to T_{MAX}, unless otherwise specified. Typical values are at V+ = +3.0V, T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	ТҮР	МАХ	UNITS		
ANALOG SWITCH									
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}			0		V+	V		
On-Resistance	Post	$V_{+} = 2.7V,$ $I_{COM_{-}} = 100mA,$	+25°C		0.5	0.8	Ω		
On-nesistance	R _{ON}	V_{NO} or V_{NC} = 1.5V	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$			0.9	52		
On-Resistance Match	ADest	$V_{+} = 2.7V,$	+25°C		0.05	0.08	Ω		
Between Channels (Note 4)	ΔR _{ON}	I_{COM} = 100mA, V_{NO} or V_{NC} = 1.5V	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$			0.09			
On-Resistance Flatness	RFLAT(ON)	V+ = 2.7V, I _{COM} = 100mA, V _{NO} or V _{NC} = 1V, 1.5V, 2V	+25°C		0.05	0.18	- Ω		
(Note 5)			T _{MIN} to T _{MAX}			0.20			
NO_ or NC_ Off-Leakage	I _{NO_(OFF)} , I _{NC_(OFF)}	V+ = 3.3V, V _{COM} _ = 0.3V, 3V, V _{NO} _ or V _{NC} _ = 3V, 0.3V	+25°C	-1		1			
Current			T _{MIN} to T _{MAX}	-5		5	nA		
	ICOM_(OFF)	$V_{+} = 3.3V,$ $V_{COM_{-}} = 0.3V, 3V$ $V_{NO_{-}} \text{ or } V_{NC_{-}} = 3V, 0.3V \text{ or}$ floating	+25°C	-1		1			
COM_ Off-Leakage Current			T _{MIN} to T _{MAX}	-5		5	nA		
COM_ On-Leakage Current	ICOM_(ON)	V+ = 3.3V, V _{COM} = 3V, 0.3V;	+25°C	-2		2			
		$V_{NO_{-}}$ or $V_{NC_{-}} = 3V$, 0.3V or floating	T_{MIN} to T_{MAX}	-10		10	nA		

ELECTRICAL CHARACTERISTICS—Single +3V Supply (continued)

 $(V + = +2.7V \text{ to } +3.6V, V_{IH} = +1.4V, V_{IL} = +0.5V, T_A = T_{MIN} \text{ to } T_{MAX}$, unless otherwise specified. Typical values are at V + = +3.0V, $T_A = +25^{\circ}C$.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	ТҮР	MAX	UNITS
SWITCH DYNAMIC CHARAC	TERISTICS						
Turn-On Time	ton	$V_{NO_{-}}, V_{NC_{-}} = 1.5V,$ $R_{I} = 50\Omega, C_{I} = 35pF,$	+25°C		18	24	ns
	UN	Figure 1	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$			28	110
Turn-Off Time	toff	V _{NO} _, V _{NC} _ = 1.5V, RL = 50Ω, CL = 35pF,	+25°C		12	16	ns
	- COL	Figure 1	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$			18	110
Break-Before-Make (Note 6)	tBBM	$V_{NO_{-}}, V_{NC_{-}} = 1.5V,$ $R_{L} = 50\Omega, C_{L} = 35pF,$	+25°C		6		ns
Dieak-Deloie-Make (Note 0)	'BBIM	Figure 1 (MAX4743)	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$	1			115
Charge Injection	Q	V _{GEN} = 0, R _{GEN} = 0, C _L = 1.0nF, Figure 3	+25°C		28		рС
NO_ or NC_ Off- Capacitance	COFF	f = 1MHz, Figure 4	+25°C		32		pF
COM_ Off-Capacitance	CCOM_(OFF)	f = 1MHz, Figure 4	+25°C		32		рF
COM_ On-Capacitance	CCOM_(ON)	f = 1MHz, Figure 4	+25°C		44		рF
-3dB On-Channel Bandwidth	BW	Signal = 0, $R_{IN} = R_{OUT} =$ 50 Ω , $C_L = 5pF$, Figure 2			100		MHz
Off-Isolation (Note 7)	VISO	$f = 1MHz$, $V_{COM} = 1V_{RMS}$, $R_L = 50\Omega$, $C_L = 5pF$, Figure 2	+25°C		-55		dB
Crosstalk (Note 8)		$f = 1MHz$, $V_{COM} = 1V_{RMS}$, $R_L = 50\Omega$, $C_L = 5pF$, Figure 2	+25°C		-110		dB
Total Harmonic Distortion	THD	f = 20Hz to 20kHz, V _{COM} = 2Vp-p, R _L = 32Ω	+25°C		0.02		%
LOGIC INPUT							
Input Logic High	VIH			1.4			V
Input Logic Low	VIL					0.5	V
Input Leakage Current	lin	$V_{IN} = 0 \text{ or } V +$		-1	0.005	1	μΑ
POWER SUPPLY							
Power-Supply Range	V+			1.6		3.6	V
Positive Supply Current	l+	V + = 3.6V, V_{IN} = 0 or V+, all channels on or off	+25°C			0.2	μA

ELECTRICAL CHARACTERISTICS—Single +1.8V Supply

 $(V + = +1.8V, V_{IH} = +1.0V, V_{IL} = 0.4V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise specified. Typical values are at $T_A = +25^{\circ}C$.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	ТҮР	МАХ	UNITS	
ANALOG SWITCH								
Analog Signal Range	V _{COM} _, V _{NO} _, V _{NC} _			0		V+	V	
On-Resistance	Ron	$I_{COM} = 10 \text{mA},$	+25°C		1.3	2.5	Ω	
		V_{NO} or V_{NC} = 0.9V	T _{MIN} to T _{MAX}			5		
NO_ or NC_ Off-Leakage	I _{NO_(OFF)} ,	V _{COM} = 0.3V, 1.5V; V _{NO} or V _{NC} = 1.5V,	+25°C	-1		1	nA	
Current	I _{NC_(OFF)}	0.3V	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$	-5		5		
0014 0111 1 0 1		V _{COM} = 0.3V, 1.5V;	+25°C	-1		1		
COM_ Off-Leakage Current	ICOM_(OFF)	V_{NO} or V_{NC} = 1.5V, 0.3V	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$	-5		5	nA	
		V _{COM} = 0.3V, 1.5V,	+25°C	-2		2		
COM_ On-Leakage Current	ICOM_(ON)	V_{NO} or V_{NC} = 0.3V, 1.5V, or floating	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$	-10		10	nA	
SWITCH DYNAMIC CHARACTE	RISTICS						1	
	ton	V_{NO} , $V_{NC} = 1.5V$, $R_L = 50\Omega$, $C_L = 35pF$, Figure 1	+25°C		25	35		
Turn-On Time			T _{MIN} to T _{MAX}			40	ns	
T 0// T		$V_{NO_{-}}, V_{NC_{-}} = 1.5V,$	+25°C		16	25		
Turn-Off Time	tOFF	$R_L = 50\Omega$, $C_L = 35pF$, Figure 1	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$			30	ns	
		$V_{\rm NO_{-}}, V_{\rm NC_{-}} = 1.5V,$	+25°C		10		1	
Break-Before-Make (Note 6)	tввм	$R_L = 50\Omega$, $C_L = 35pF$, Figure 1 (MAX4743)	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$	T _{MIN} to T _{MAX} 1			ns	
Charge Injection	Q	$V_{GEN} = 0$, $R_{GEN} = 0$, $C_L = 1$ nF, Figure 2	+25°C		16		рС	
Off-Isolation (Note 7)	VISO	$ f = 1 MHz, V_{NO_} = V_{NC_} $ $ = 1 V_{RMS}, R_L = 50 \Omega, $ $ C_L = 5 pF, Figure 2 $	+25°C		-50		dB	
Crosstalk (Note 8)		$\label{eq:f_comparameters} \begin{split} f &= 1 MHz, \ V_{COM_} = 1 V_{RMS}, \\ R_L &= 50 \Omega, \\ C_L &= 5 pF, \ Figure \ 2 \end{split}$	+25°C		-110		dB	

ELECTRICAL CHARACTERISTICS—Single +1.8V Supply (continued)

 $(V + = +1.8V, V_{IH} = +1.0V, V_{IL} = 0.4V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise specified. Typical values are at $T_A = +25^{\circ}C$.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	ТҮР	MAX	UNITS
LOGIC INPUT							
Input Logic High	VIH			1			V
Input Logic Low	VIL					0.4	V
Input Leakage Current	lin	$V_{IN} = 0 \text{ or } V_{+}$		-1		1	μA

Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value is a maximum, is used in this data sheet.

Note 3: SOT23 packaged parts are 100% tested at +25°C. Limits across the full temperature range are guaranteed by design and correlation. μMAX packaged parts -40°C specifications are guaranteed by design.

Note 4: $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$.

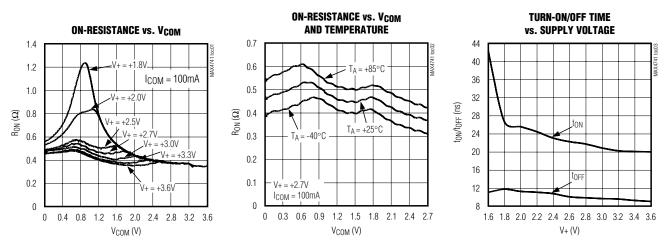
 $(T_A = +25^{\circ}C, unless otherwise noted.)$

Note 5: Flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured over the specified analog signal ranges.

Note 6: Guaranteed by design.

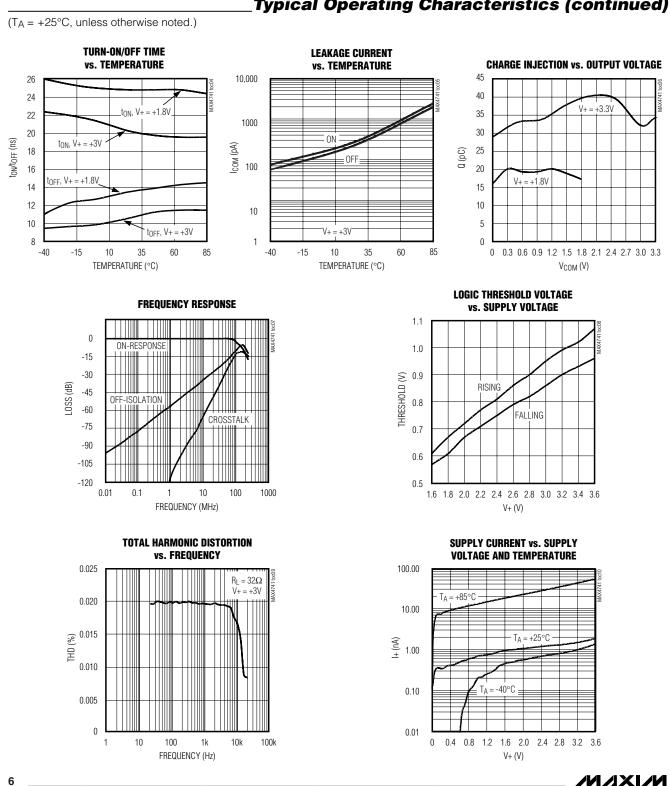
Note 7: Off-Isolation = 20log₁₀(V_{COM}_/V_{NO}_), V_{COM}_ = output, V_{NO}_ = input to off switch.

Note 8: Between two switches.



Typical Operating Characteristics

MAX4741/MAX4742/MAX4743



Typical Operating Characteristics (continued)

MAX4741/MAX4742/MAX4743

Pin Description

		Р	IN				
MAX	4741	MAX	(4742	MAX4743		NAME	FUNCTION
μ ΜΑΧ	SOT23-8	μ ΜΑΧ	SOT23-8	μ ΜΑΧ	SOT23-8		
1	8		_	1	8	NO1	Analog Switch 1 Normally Open
—	_	1	8	—	_	NC1	Analog Switch 1 Normally Closed
2	7	2	7	2	7	COM1	Analog Switch 1 Common
3	6	3	6	3	6	IN2	Logic Control Input Switch 2
4	5	4	5	4	5	GND	Ground
5	3	_	—	_	—	NO2	Analog Switch 2 Normally Open
—	_	5	3	5	3	NC2	Analog Switch 2 Normally Closed
6	4	6	4	6	4	COM2	Analog Switch 2 Common
7	1	7	1	7	1	IN1	Logic Control Input Switch 1
8	2	8	2	8	2	V+	Positive Supply Voltage

Detailed Description

The MAX4741/MAX4742/MAX4743 are low 0.8Ω max (at $V_{+} = +3V$) on-resistance, low-voltage, dual analog switches that operate from a +1.6V to +3.6V single supply. CMOS switch construction allows switching analog signals that are within the supply voltage range (GND to V+).

When powered from a +3V supply, the 0.8Ω max R_{ON} allows high continuous currents to be switched in a variety of applications.

Applications Information

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, followed by NO_, NC_, or COM .

Although it is not required, power-supply bypassing improves noise margin and prevents switching noise propagation from the V+ supply to other components. A 0.1µF capacitor, connected from V+ to GND, is adequate for most applications.

The MAX4741/MAX4742/MAX4743 logic inputs can be driven up to +3.6V regardless of the supply voltage. For example, with a +1.8V supply, IN_ may be driven low to GND and high to +3.6V. Driving IN_ rail-to-rail minimizes power consumption.

Analog Signal Levels

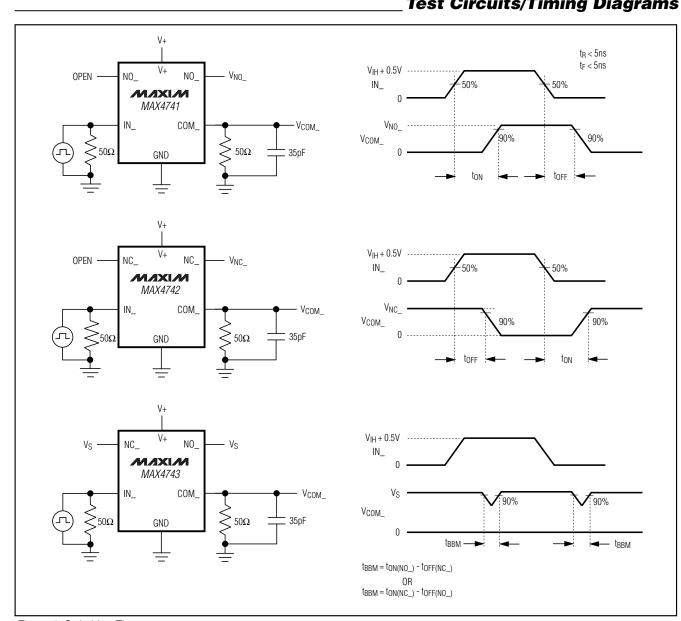
Analog signals that range over the entire supply voltage (V+ to GND) can be passed with very little change in onresistance (see Typical Operating Characteristics). The switches are bidirectional, so the NO_, NC_, and COM_ pins can be used as either inputs or outputs.

Layout

High-speed switches require proper layout and design procedures for optimum performance. Reduce stray inductance and capacitance by keeping traces short and wide. Ensure that bypass capacitors are as close to the device as possible. Use large ground planes where possible.

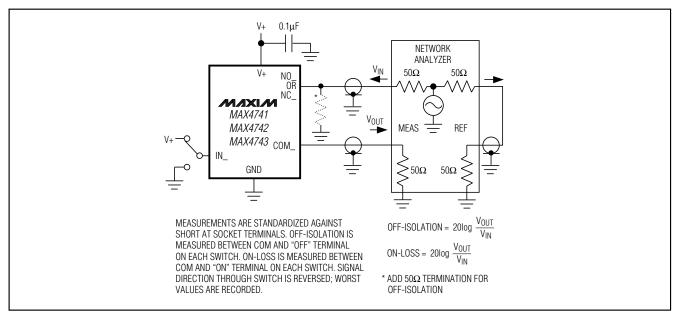
M/IXI/M

Logic Inputs



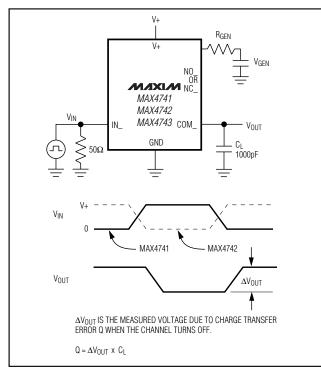
Test Circuits/Timing Diagrams

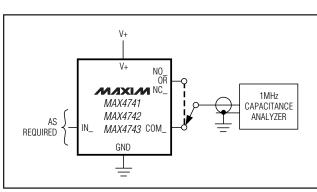
Figure 1. Switching Times



_Test Circuits/Timing Diagrams (continued)

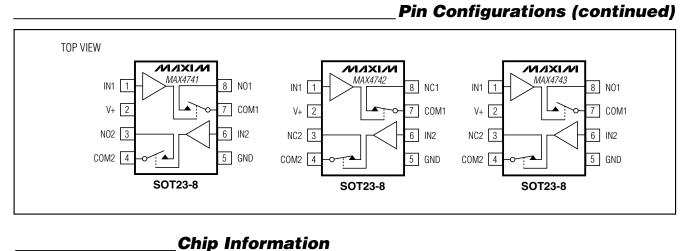
Figure 2. Off-Isolation, On-Loss, and Crosstalk





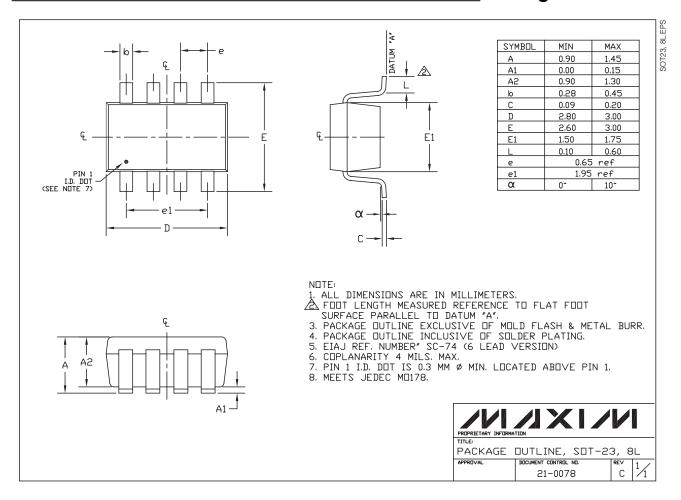


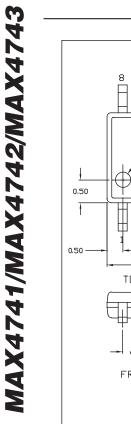
MAX4741/MAX4742/MAX4743



TRANSISTOR COUNT = 121 PROCESS = CMOS

Package Information





4X S JEDEC 8 MILLIMETERS MILLIMETERS INCHES INCHES MAX MAX MIN MAX MIN MIN MAX MIN 0.037 0.043 0.94 1.10 0.043 1.10 Δ A1 0.002 0.006 0.05 0.15 0.002 0.006 0.05 0.15 В 0.010 0.014 0.25 0.36 0.010 0.016 0.25 0.40 0.005 0.007 0.005 0.009 0.13 С 0.13 0.18 0.23 0.116 0.120 3.05 D 2.95 0.114 0.122 2.9 3.1 0.02 <u>ie bsc</u> 0.65 BSC 0.0256 BSC 0.64 BSC Ε Н Ø0.50±0.01 F 0.120 2.95 3.05 0.114 0.122 2.9 3.1 0.116 4.78 Н 0.188 0.198 5.03 0.193 BSC 4.9 BSC 0.40 0.70 0.016 0.026 0.41 0.66 0.016 0.027 L ٥° 6° 0° 6° 0° 6٩ 0° 6° α S 0.0207 BSC 0.5250 BSC 1 BOTTOM VIEW TOP VIEW A1 С α SIDE VIEW FRONT VIEW NOTES: 1. D&E DO NOT INCLUDE MOLD FLASH. 2. MOLD FLASH OR PROTRUSIONS NOT TO EXCEED 0.15MM (.006"). TITLE PACKAGE DUTLINE, 8L uMAX 3. CONTROLLING DIMENSION: MILLIMETERS. 4. MEETS JEDEC MO-187. APPROVAL DOCUMENT CONTROL NO. 1 21-0036 Ι

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Package Information (continued)

8LUMAXD.EPS